

Research on Fatigue For AlN - Cu Plate Jointed By DBC Method For Semi-Conductor Substrate

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Abstract. A elastic-plastic analysis of AlN/Cu jointing plate was performed by FEM to study the residual stress produced in the jointing-cooling process. This residual stress due to the difference of thermal expansion coefficient between ceramics and metal was analyzed, considering the presence of initial defects in ceramics. A static fatigue life was estimated based on a stress intensity factor of the supper-posed stress of the residual stress and the bending stress in ceramics of AlN/Cu jointing plate with the various thickness of Al₂O₃ layer.

I. INTRODUCTION

According to the needs for the high power electric, the high integration and the modular structure of semi-conductor parts used for industrial machines, the AlN/Cu semi-conductor plate has been developed. This semi-conductor plate was jointed by ceramics and metal with DBC (direct bonding copper) method. The strength reliability of the AlN/Cu semi-conductor plate is afraid to be effected by the residual stress produced in the process of jointing-cooling. It becomes to be known that the residual stress is very important to estimate the long-period reliability of the AlN/Cu semi-conductor. In our paper, The static fatigue strength and the fracture mechanism of the AlN/Cu semi-conductor plate were discussed from the viewpoint of fracture mechanics, considering the presence of initial defects in ceramics, and a probabilistic fracture strength analysis was carried out on the basis of the fracture mechanics from one of innumerable initial microscopic defects. Also, the residual stress with various thickness of Al₂O₃ layer was discussed and the estimation method of the static fatigue life for AlN/Cu semi-conductor plate was proposed..

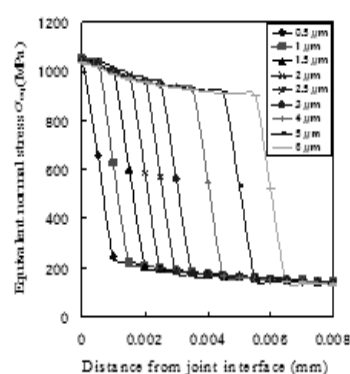


Fig.1 Distribution of σ_{eq} toward depth direction

II. TEST AND ANALYSIS METHOD

A test specimens is the AlN/Cu semi-conductor plate jointed Cu plate(B0.3×W8×L17) with AlN plate(B0.8×W10×L40) at high temperature (1065 °C -1083 °C) in the oxygen concentration of 80~3900ppm with DBC method. Four-point bending tests were conducted for the test specimens at the cross-head speed of 0.04 mm/min, at room temperature in atmosphere. The elastic-plastic analysis was done about experimental rupture loads by the 4-point bending tests with FEM. The elastic-plastic analysis was also done for the residual stress produced in the process of jointing-cooling.

The thickness of Al_2O_3 layer on the surface of AlN was varied in order to study its effect on the residual stress and the static fatigue strength.

III. TEST AND ANALYSIS RESULT

The fracture of ceramics occurs usually from one of innumerable initial defects under a multi-axial stress. The equivalent normal stress considering shear stress about initial defects under the multi-axial stress is given (1) by

$$\sigma_{eq} = \sqrt{\sigma_x^2 + \frac{4}{(2-\nu)^2} \tau_{xy}^2} \quad \dots\dots\dots (1) \text{ where, } \sigma_x$$

is a normal stress, τ_{xy} is a shear stress, ν is Poisson's ratio.

A. The residual stress produced in the process of jointing-cooling

The residual stress produced in the process of jointing-cooling indicates the maximum value at the second node from the jointing interface in the side of ceramics. The equivalent normal stress distribution toward depth direction is shown in Fig.1. Next, the stress intensity factor K_{Ieq} at the tip of a defect was analyzed against this equivalent normal stress σ_{eq} . Assuming that there is a surface semi-circle crack in the depth direction distribution of the residual stress containing the maximum value, the stress intensity factor K_{Ieq} is given by

$$K_{Ieq} = 2\sqrt{\frac{a}{\pi}} \int_0^a \frac{\sigma_{eq}(y)}{\sqrt{a^2 - y^2}} dy \quad \dots\dots\dots (2)$$

where, a is the length of a surface semi-circle crack, y is a distance toward depth direction.

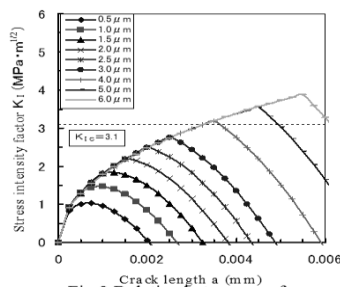


Fig.2 Relation between surface crack length and stress intensity factor

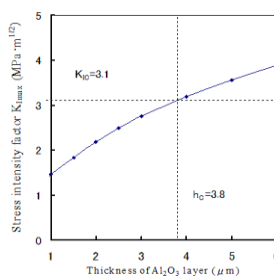


Fig.3 Relation between stress intensity factor and thickness of Al_2O_3 layer

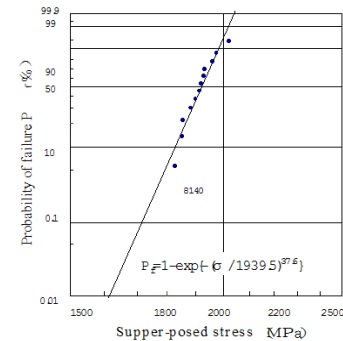


Fig.4 Weibull distribution of super-posed stress

With every thickness of Al_2O_3 layer, the relation between the stress intensity factor K_{Ieq} and the crack length a is shown in Fig.2. As seen in Fig.2, the K_{Ieq} has the maximum value $K_{I max}$ in the case of a crack tip reaching the interface of AlN and Al_2O_3 . On the other hand, the relation between the $K_{I max}$ and the Al_2O_3 layer thickness h is given in Fig.3. it is illustrated that the K_{Ieq} is more than the fracture toughness K_{IC} ($3.1 \text{ MPa m}^{1/2}$) of AlN when the h is more than $3.8 \mu\text{m}$. Therefore, if there is the defect penetrating through the Al_2O_3 layer more than $3.8 \mu\text{m}$ in thickness, it can be estimated that the fracture will be caused by the crack growth toward AlN under the residual stress. Conversely, if Al_2O_3 layer is thinner than $3.8 \mu\text{m}$, fracture wouldn't occur only due to the residual stress.

B. the analysis of 4-point bending load

For the purpose of estimating the true fracture strength $\tilde{\sigma}_{f(4B)}$ of the AlN/Cu jointing specimens considering the residual stress, the equivalent super-posed stress $\tilde{\sigma}_{eq}$ of both the residual stress σ_R was analyzed. The fracture strength was discussed using this $\tilde{\sigma}_{eq}$. The probability of fracture P_f can be approximated well by two-parameter Weibull distribution as shown in Fig.4.

Weibull modulus m is 37.6 and scale parameter σ_0 is 1939.5 MPa. that a surface semi-circle crack with the length of a exists, the stress intensity factor $K_{I(4B)}$ at this crack tip against is given (3)

$$K_{I(4B)} = H \frac{\sigma_b \sqrt{\pi b}}{E(k)} F\left(\frac{b}{t}, \frac{b}{a}, \frac{a}{w}, \phi\right) \dots (3)$$

where ϕ is the angle of radius direction against x-z plane direction. In the critical position of the semi-circle crack ($\phi = 0^\circ$), the $K_{I(4B)}$ have a maximum value. The relation between $K_{I(4B)}$ ($\phi = 0^\circ$) and a is shown in Fig.5.

Because the $K_{I(4B)}$ in the position of ($\phi = 0^\circ$) is more than the $K_{I(4B)}$ in the position of ($\phi = 90^\circ$), a surface penetrating crack can be formed at first. The $K_{I(4B)}$ at the surface penetrating crack tip against 4-point bending stress is given

$$K_{I(4B)} = f\left(\frac{a}{W}\right) \frac{6M}{BW^2} \sqrt{a} \quad (4)$$

where a is the surface penetrating crack depth. The critical condition judging fracture occurrence is given by $K_{Ieq} = \varphi \tilde{\sigma}_{eq} \sqrt{\pi c_b}$ (5)

where, φ is a shape factor, C_b is an initial surface defect size. If the K_{Ieq} is more than the K_{IC} of AlN, fracture will occur. Based on Eq.(5), the C_b can be estimated and expressed by

$$c_b = \frac{1}{\pi} (K_{IC} / \varphi \sigma)^2 \quad (6)$$

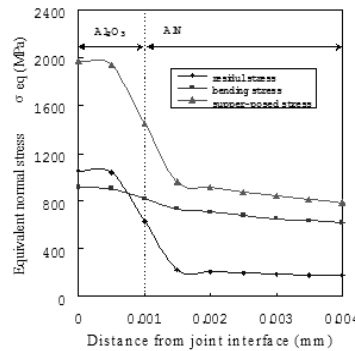


Fig.5 Equivalent normal stress toward depth direction

where, the shape factor φ is 0.73 and K_{IC} of AlN is $3.1 \text{ MPa} \cdot \text{mm}^{1/2}$. As the result of estimation, the relation between the C_b causing fracture and the $\tilde{\sigma}_{eq}$ is given as shown in Figs.5. But if there is a penetrating crack, the K_{Ieq} of the penetrating crack with depth of $1.5 \mu\text{m}$ is more than K_{IC} of AlN. By the way, as the Al_2O_3 layer is $1 \mu\text{m}$ in thickness, the crack tip with depth of $1.5 \mu\text{m}$ becomes to reach the inside of AlN, and so rapid unstable fracture will occur. The $\tilde{\sigma}_{f(4B)}$ is dominated by the unstable fracture just when the K_{Ieq} reaches the K_{IC} of AlN. Therefore the strength of the semiconductor plate is dominated by the strength of AlN.

IV. THE STATIC FATIGUE PROPERTY OF SEMI-CONDUCTOR PLATE JOINTED BY DBC METHOD

It is found from Fig.1 and Fig.3 that the σ_{Rmax} in the Al_2O_3 layer is almost constant without regard to increase of the h , but the K_{Imax} increases with increase of the h . Therefore, from viewpoint of fracture mechanics, the static fatigue strength decreases with increase of the h . As a expression to estimate the static fatigue life from the h , Therefore the static fatigue life can be estimated by Eq.(7).

$$t_f = \frac{1}{\tilde{\sigma}_{eq}^n} \left(\frac{K_{IC}}{\sqrt{\pi h}} \right)^n \dots\dots\dots (7)$$

where n is a crack growth, The $\tilde{\sigma}_{eq}$ consists of the σ_R and the $\sigma_{(4B)}$. In the practical use of the semi-conductor plate, thermal stress σ_{th} may be considered instead of the $\sigma_{(4B)}$. But, as σ_{th} is much more than $\sigma_{(4B)}$, the thickness of Al_2O_3 layer was found to dominate greatly the static fatigue life.

V. CONCLUSION

The residual stress produced in the process of jointing-cooling was analyzed by FEM method. Taking the notice of the superposed stress of both residual stress, it was found that this superposed stress is much more than by conventional same AlN materials. As for estimating the strength reliability of the semi-conductor plate, it was found to be very necessary to consider the residual stress. Also, the static fatigue properties with various thickness of Al_2O_3 layer was clarified through the concept of fracture mechanism and this static fatigue life could be quantitatively estimated based on the thickness of Al_2O_3 layer.

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